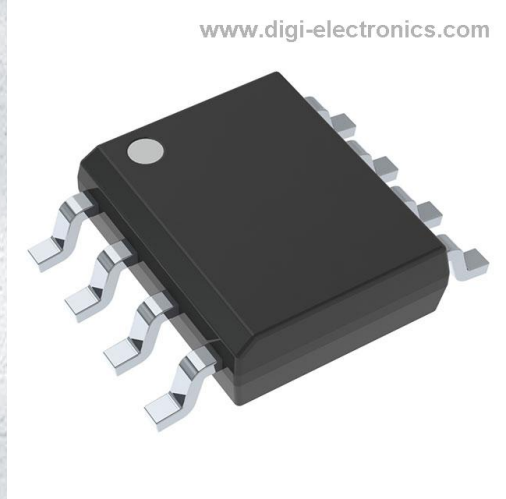
THS4061IDRG4 Datasheet



DiGi Electronics Part Number	THS4061IDRG4-DG
Manufacturer	Texas Instruments
Manufacturer Product Number	THS4061IDRG4
Description	IC VOLTAGE FEEDBACK 1 CIRC 8SOIC
Detailed Description	Voltage Feedback Amplifier 1 Circuit 8-SOIC

https://www.DiGi-Electronics.com

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
THS4061IDRG4	Texas Instruments
Series:	Product Status:
-	Discontinued at Digi-Key
Amplifier Type:	Number of Circuits:
Voltage Feedback	1
Output Type:	Slew Rate:
-	400V/µs
-3db Bandwidth:	Current - Input Bias:
180 MHz	3 µA
Voltage - Input Offset:	Current - Supply:
2.5 mV	7.8mA
Current - Output / Channel:	Voltage - Supply Span (Min):
115 mA	9 V
Voltage - Supply Span (Max):	Operating Temperature:
33 V	-40°C ~ 85°C
Mounting Type:	Package / Case:
Surface Mount	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package:	Base Product Number:
8-SOIC	THS4061

Environmental & Export classification

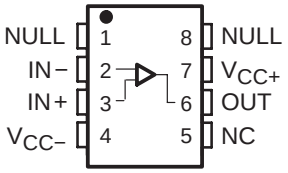
RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.33.0001	

THS4061, THS4062
180-MHz HIGH-SPEED AMPLIFIERS

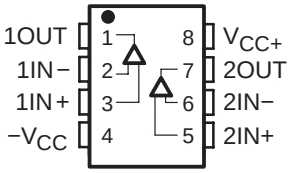
SLOS234E − DECEMBER 1998 − REVISED DECEMBER 2003

- **High Speed**
  - **180 MHz Bandwidth (G = 1, −3 dB)**
  - **400 V/μs Slew Rate**
  - **40-ns Settling Time (0.1%)**
- **High Output Drive, I_O = 115 mA (typ)**
- **Excellent Video Performance**
  - **75 MHz 0.1 dB Bandwidth (G = 1)**
  - **0.02% Differential Gain**
  - **0.02° Differential Phase**
- **Very Low Distortion**
  - **THD = −72 dBc at f = 1 MHz**
- **Wide Range of Power Supplies**
  - **V_{CC} = ±5 V to ±15 V**
- **Available in Standard SOIC, MSOP PowerPAD™, JG, or FK Package**
- **Evaluation Module Available**

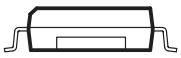
THS4061
JG, D AND DGN PACKAGE
(TOP VIEW)



THS4062
D AND DGN PACKAGE
(TOP VIEW)

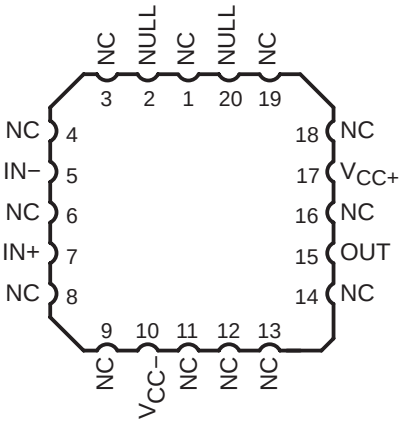


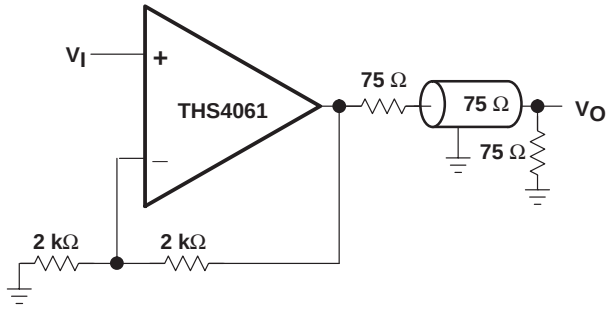
NC − No internal connection



Cross-Section View Showing
PowerPAD Option (DGN)

THS4061
FK PACKAGE
(TOP VIEW)





LINE DRIVER (G = 2)

description

The THS4061 and THS4062 are general-purpose, single/dual, high-speed voltage feedback amplifiers ideal for a wide range of applications including video, communication, and imaging. The devices offer very good ac performance with 180-MHz bandwidth, 400-V/μs slew rate, and 40-ns settling time (0.1%). The THS4061/2 are stable at all gains for both inverting and noninverting configurations. These amplifiers have a high output drive capability of 115 mA and draw only 7.8 mA supply current per channel. Excellent professional video results can be obtained with the low differential gain/phase errors of 0.02%/0.02° and wide 0.1 db flatness to 75 MHz. For applications requiring low distortion, the THS4061/2 is ideally suited with total harmonic distortion of −72 dBc at f = 1 MHz.

CAUTION: The THS4061 and THS4062 provide ESD protection circuitry. However, permanent damage can still occur if this device is subjected to high-energy electrostatic discharges. Proper ESD precautions are recommended to avoid any performance degradation or loss of functionality

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments Incorporated.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

RELATED DEVICES	
DEVICE	**DESCRIPTION**
THS4011/2	290-MHz Low Distortion High-Speed Amplifiers
THS4031/2	100-MHz Low Noise High Speed-Amplifiers
THS4061/2	180-MHz High-Speed Amplifiers

AVAILABLE OPTIONS

T_A	NUMBER OF CHANNELS	PACKAGED DEVICES				MSOP SYMBOL	EVALUATION MODULES
		PLASTIC SMALL OUTLINE† (D)	PLASTIC MSOP† (DGN)	CERAMIC DIP (JG)	CHIP CARRIER (FK)		
0°C to 70°C	1	THS4061CD	THS4061CDGN	—	—	TIABS	THS4061EVM
	2	THS4062CD	THS4062CDGN	—	—	TIABM	THS4062EVM
−40°C to 85°C	1	THS4061ID	THS4061IDGN	—	—	TIABT	—
	2	THS4062ID	THS4062IDGN	—	—	TIABN	—
−55°C to 125°C	1	—	—	THS4061MJG	THS4061MFK	—	—

† The D and DGN packages are available taped and reeled. Add an R suffix to the device type (i.e., THS4061CDGNR).

functional block diagram

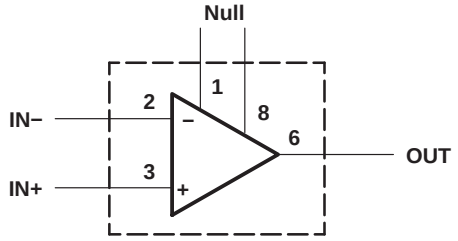

Figure 1. THS4061 − Single Channel

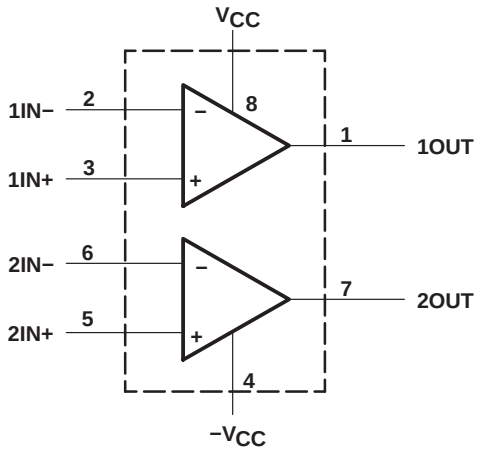

Figure 2. THS4062 − Dual Channel

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, $V_{CC}+$ to $V_{CC}-$ . . . . . 33 V
Input voltage, V_I . . . . . $\pm V_{CC}$
Output current, I_O . . . . . 150 mA
Differential input voltage, V_{IO} . . . . . ±4 V
Continuous total power dissipation . . . . . See Dissipation Rating Table
Maximum junction temperature, T_J . . . . . 150°C
Operating free-air temperature, T_A: C-suffix . . . . . 0°C to 70°C
I-suffix . . . . . −40°C to 85°C
M-suffix . . . . . −55°C to 125°C
Storage temperature, T_{stg} . . . . . −65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds, D and DGN package . . . . . 300°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds, JG package . . . . . 300°C
Case temperature for 60 seconds, FK package . . . . . 260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING	$T_A = 85°C$ POWER RATING	$T_A = 125°C$ POWER RATING
D	740 mW	6 mW/°C	475 mW	385 mW	—
DGN‡	2.14 W	17.1 mW/°C	1.37 W	1.11 W	—
JG	1057 mW	8.4 mW/°C	627 mW	546 mW	210 mW
FK	1375 mW	11 mW/°C	880 mW	715 mW	275 mW

‡ The DGN package incorporates a PowerPAD on the underside of the device. This acts as a heatsink and must be connected to a thermal dissipation plane for proper power dissipation. Failure to do so can result in exceeding the maximum specified junction temperature, which could permanently damage the device.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, $V_{CC}+$ and $V_{CC}-$	Dual supply	±4.5		±16	V
	Single supply	9		32	
Operating free-air temperature, T_A	C-suffix	0		70	°C
	I-suffix	−40		85	
	M-suffix	−55		125	

electrical characteristics at T_A = 25°C, V_{CC} = ±15 V, R_L = 150 Ω (unless otherwise noted)

dynamic performance

PARAMETER		TEST CONDITIONS†		THS4061C/I, THS4062C/I MIN	TYP	MAX	UNIT
BW	Dynamic performance small-signal bandwidth (−3 dB)	V_{CC} = ±5 V	Gain = 1		180		MHz
		V_{CC} = ±15 V	Gain = −1		50		MHz
		V_{CC} = ±5 V			50		
	Bandwidth for 0.1 dB flatness	V_{CC} = ±15 V	Gain = 1		75		MHz
		V_{CC} = ±5 V			20		
SR	Slew rate	V_{CC} = ±15 V	Gain = −1		400		V/μs
		V_{CC} = ±5 V			350		
t_s	Settling time to 0.1%	V_{CC} = ±15 V, 5-V step (0 V to 5 V)	Gain = −1		40		ns
		V_{CC} = ±5 V, V_O = −2.5 V to 2.5 V,			40		
	Settling time to 0.01%	V_{CC} = ±15 V, 5-V step (0 V to 5 V)	Gain = −1		140		ns
		V_{CC} = ±5 V, V_O = −2.5 V to 2.5 V,			150		

† Full range = 0°C to 70°C for C suffix and −40°C to 85°C for I suffix

noise/distortion performance

PARAMETER		TEST CONDITIONS†		THS4061C/I, THS4062C/I MIN	TYP	MAX	UNIT
THD	Total harmonic distortion	f = 1 MHz			−72		dBc
V_n	Input voltage noise	f = 10 kHz, V_{CC} = ±5 V or ±15 V			14.5		nV/√Hz
I_n	Input current noise	f = 10 kHz, V_{CC} = ±5 V or ±15 V			1.6		pA/√Hz
	Differential gain error	Gain = 2, NTSC, 40 IRE modulation	V_{CC} = ±15 V		0.02 %		
			V_{CC} = ±5 V		0.02 %		
	Differential phase error	Gain = 2, NTSC, 40 IRE modulation	V_{CC} = ±15 V		0.02°		
			V_{CC} = ±5 V		0.06°		
	Channel-to-channel crosstalk (THS4062 only)	V_{CC} = ±5 V or ±15 V, f = 1 MHz			65		dB

† Full range = 0°C to 70°C for C suffix and −40°C to 85°C for I suffix

dc performance

PARAMETER		TEST CONDITIONS†		THS4061C/I, THS4062C/I MIN	TYP	MAX	UNIT
	Open loop gain	V_{CC} = ±15 V, V_O = ±10 V, R_L = 1 kΩ	T_A = 25°C	5	15		V/mV
			T_A = full range	4			
		V_{CC} = ±5 V, V_O = ±2.5 V, R_L = 1 kΩ	T_A = 25°C	2.5	8		V/mV
			T_A = full range	2			
V_{OS}	Input offset voltage	V_{CC} = ±5 V or ±15 V	T_A = full range		2.5	8	mV
	Offset drift	V_{CC} = ±5 V or ±15 V			15		μV/°C
I_{IB}	Input bias current	V_{CC} = ±5 V or ±15 V	T_A = full range		3	6	μA
I_{OS}	Input offset current	V_{CC} = ±5 V or ±15 V	T_A = full range		75	250	nA
	Offset current drift	T_A = full range			0.3		nA/°C

† Full range = 0°C to 70°C for C suffix and −40°C to 85°C for I suffix

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

electrical characteristics at T_A = 25°C, V_{CC} = ±15 V, R_L = 150 Ω (unless otherwise noted) (continued)

input characteristics

PARAMETER		TEST CONDITIONS†			THS4061C/I, THS4062C/I			UNIT
					MIN	TYP	MAX	
V_{ICR}	Common-mode input voltage range	V_{CC} = ±15 V			±13.8	±14.1		V
		V_{CC} = ±5 V			±3.8	±4.3		
CMRR	Common mode rejection ratio	V_{CC} = ±15 V,	V_{ICR} = ±12 V	T_A = full range	70	110		dB
		V_{CC} = ±5 V,	V_{ICR} = ±2.5 V		70	95		
R_I	Input resistance					1		MΩ
C_i	Input capacitance					2		pF

† Full range = 0°C to 70°C for C suffix and −40°C to 85°C for I suffix

output characteristics

PARAMETER		TEST CONDITIONS†		THS4061C/I, THS4062C/I			UNIT
				MIN	TYP	MAX	
V_O	Output voltage swing	V_{CC} = ±15 V	R_L = 250 Ω	±11.5	±12.5		V
		V_{CC} = ±5 V	R_L = 150 Ω	±3.2	±3.5		
		V_{CC} = ±15 V	R_L = 1 kΩ	±13	±13.5		V
		V_{CC} = ±5 V		±3.5	±3.7		
I_O	Output current	V_{CC} = ±15 V	R_L = 20 Ω	80	115		mA
		V_{CC} = ±5 V		50	75		
I_{SC}	Short-circuit current	V_{CC} = ±15 V			150		mA
R_O	Output resistance	Open loop			12		Ω

† Full range = 0°C to 70°C for C suffix and −40°C to 85°C for I suffix

power supply

PARAMETER		TEST CONDITIONS†		THS4061C/I, THS4062C/I			UNIT
				MIN	TYP	MAX	
V_{CC}	Supply voltage operating range	Dual supply		±4.5		±16.5	V
		Single supply		9		33	
I_{CC}	Quiescent current (per amplifier)	V_{CC} = ±15 V	T_A = full range		7.8	10.5	mA
		V_{CC} = ±5 V			7.3	10	
PSRR	Power supply rejection ratio	V_{CC} = ±5 V or ±15 V	T_A = 25°C	70	78		dB
			T_A = full range	68			

† Full range = 0°C to 70°C for C suffix and −40°C to 85°C for I suffix

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

electrical characteristics at T_A = 25°C, V_{CC} = ±15 V, R_L = 150 Ω (unless otherwise noted)

dynamic performance

PARAMETER		TEST CONDITIONS†		THS4061M MIN	THS4061M TYP	THS4061M MAX	UNIT
BW	Unity-gain bandwidth	Closed loop, R_L = 1 kΩ	V_{CC} = ±15 V	*140	180		MHz
	Dynamic performance small-signal bandwidth (−3 dB)	V_{CC} = ±15 V	Gain = 1		180		MHz
		V_{CC} = ±5 V			180		
		V_{CC} = ±15 V	Gain = −1		50		MHz
		V_{CC} = ±5 V			50		
	Bandwidth for 0.1 dB flatness	V_{CC} = ±15 V	Gain = 1		75		MHz
		V_{CC} = ±5 V			20		
SR	Slew rate	V_{CC} = ±15 V R_L = 1 kΩ		*400	500		V/µs
t_S	Settling time to 0.1%	V_{CC} = ±15 V, 5-V step (0 V to 5 V)	Gain = −1		40		ns
		V_{CC} = ±5 V, V_O = −2.5 V to 2.5 V,			40		
	Settling time to 0.01%	V_{CC} = ±15 V, 5-V step (0 V to 5 V)	Gain = −1		140		ns
		V_{CC} = ±5 V, V_O = −2.5 V to 2.5 V,			150		

† Full range = −55°C to 125°C for M suffix
*This parameter is not tested.

noise/distortion performance

PARAMETER		TEST CONDITIONS†		THS4061M MIN	THS4061M TYP	THS4061M MAX	UNIT
THD	Total harmonic distortion	f = 1 MHz			−72		dBc
V_n	Input voltage noise	f = 10 kHz, V_{CC} = ±5 V or ±15 V			14.5		nV/√Hz
I_n	Input current noise	f = 10 kHz, V_{CC} = ±5 V or ±15 V			1.6		pA/√Hz
	Differential gain error	Gain = 2, NTSC, 40 IRE Modulation	V_{CC} = ±15 V		0.02		%
			V_{CC} = ±5 V		0.02		
	Differential phase error	Gain = 2, NTSC, 40 IRE Modulation	V_{CC} = ±15 V		0.02°		
			V_{CC} = ±5 V		0.06°		

† Full range = −55°C to 125°C for M suffix

dc performance

PARAMETER		TEST CONDITIONS†		THS4061M MIN	THS4061M TYP	THS4061M MAX	UNIT
	Open loop gain	V_{CC} = ±15 V, V_O = ±10 V, R_L = 1 kΩ	T_A = full range	5	9		V/mV
		V_{CC} = ±5 V, V_O = ±2.5 V, R_L = 1 kΩ		2.5	6		
V_{IO}	Input offset voltage	V_{CC} = ±5 V or ±15 V R_L = 1 kΩ	T_A = 25°C		2.5	8	mV
			T_A = full range			9	mV
	Offset drift	V_{CC} = ±5 V or ±15 V R_L = 1 kΩ	T_A = full range		15		µV/°C
I_{IB}	Input bias current	V_{CC} = ±5 V or ±15 V R_L = 1 kΩ	T_A = full range		3	6	µA
I_{IO}	Input offset current	V_{CC} = ±5 V or ±15 V R_L = 1 kΩ	T_A = full range		75	250	nA
	Offset current drift	V_{CC} = ±5 V or ±15 V R_L = 1 kΩ	T_A = full range		0.3		nA/°C

† Full range = −55°C to 125°C for M suffix

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

electrical characteristics at T_A = full range, V_{CC} = ±15 V, R_L = 1 kΩ (unless otherwise noted) (continued)

input characteristics

PARAMETER		TEST CONDITIONS†		THS4061M			UNIT
				MIN	TYP	MAX	
V_{ICR}	Common-mode input voltage range	V_{CC} = ±15 V		±13.8	±14.1		V
		V_{CC} = ±5 V		±3.8	±4.3		
CMRR	Common mode rejection ratio	V_{CC} = ±15 V,	V_{ICR} = ±12 V	70	86		dB
		V_{CC} = ±5 V,	V_{ICR} = ±2.5 V	80	90		
R_I	Input resistance				1		MΩ
C_i	Input capacitance				2		pF

† Full range = −55°C to 125°C for M suffix

output characteristics

PARAMETER		TEST CONDITIONS†		THS4061M			UNIT
				MIN	TYP	MAX	
V_O	Output voltage swing	V_{CC} = ±15 V	R_L = 250 Ω	±12	±13.1		V
		V_{CC} = ±5 V	R_L = 150 Ω	±3.2	±3.5		
		V_{CC} = ±15 V	R_L = 1 kΩ	±13	±13.5		V
		V_{CC} = ±5 V		±3.5	±3.7		
I_O	Output current	V_{CC} = ±15 V	R_L = 20 Ω	70	115		mA
		V_{CC} = ±5 V		50	75		
I_{SC}	Short-circuit current	V_{CC} = ±15 V	T_A = 25°C		150		mA
R_O	Output resistance	Open loop			12		Ω

† Full range = −55°C to 125°C for M suffix

power supply

PARAMETER		TEST CONDITIONS†		THS4061M			UNIT
				MIN	TYP	MAX	
V_{CC}	Supply voltage operating range	Dual supply		±4.5		±16.5	V
		Single supply		9		33	
I_{CC}	Quiescent current	V_{CC} = ±15 V	T_A = 25°C		7.8	9	mA
		V_{CC} = ±5 V			7.3	8.5	
		V_{CC} = ±15 V	T_A = full range			11	
		V_{CC} = ±5 V				10.5	
PSRR	Power supply rejection ratio	V_{CC} = ±5 V or ±15 V	T_A = 25°C	76	80		dB
			T_A = full range	74	78		

† Full range = −55°C to 125°C for M suffix

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

TYPICAL CHARACTERISTICS

			FIGURE
I_{IB}	Input bias current	vs Free-air temperature	3
V_{IO}	Input offset voltage	vs Free-air temperature	4
	Open-loop gain	vs Frequency	5
	Phase	vs Frequency	5
	Differential gain	vs Number of loads	6, 8
	Differential phase	vs Number of loads	7, 9
	Closed-loop gain	vs Frequency	10, 11
	Output amplitude	vs Frequency	12, 13
CMRR	Common-mode rejection ratio	vs Frequency	14
PSRR	Power supply rejection ratio	vs Frequency	15
		vs Free-air temperature	16
$V_{O(PP)}$	Output voltage swing	vs Supply voltage	17
I_{CC}	Supply current	vs Free-air temperature	18
E_{nv}	Noise spectral density	vs Frequency	19
THD	Total harmonic distortion	vs Frequency	20, 21
	Crosstalk	vs Frequency	22, 23

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

TYPICAL CHARACTERISTICS

INPUT BIAS CURRENT vs FREE-AIR TEMPERATURE

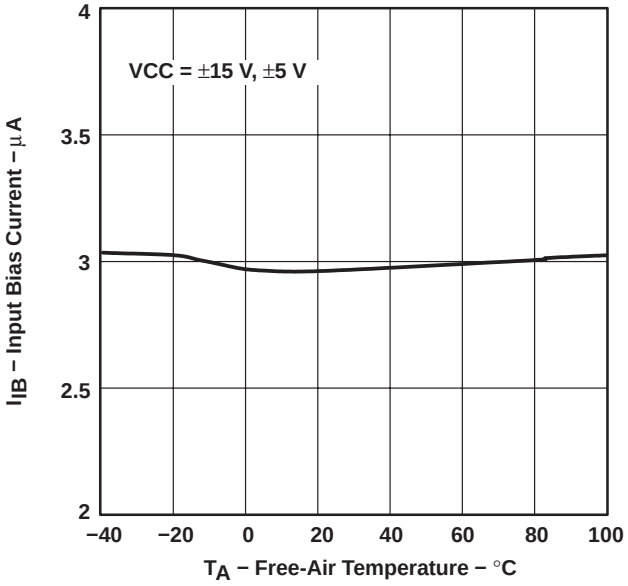

Figure 3

INPUT OFFSET VOLTAGE vs FREE-AIR TEMPERATURE

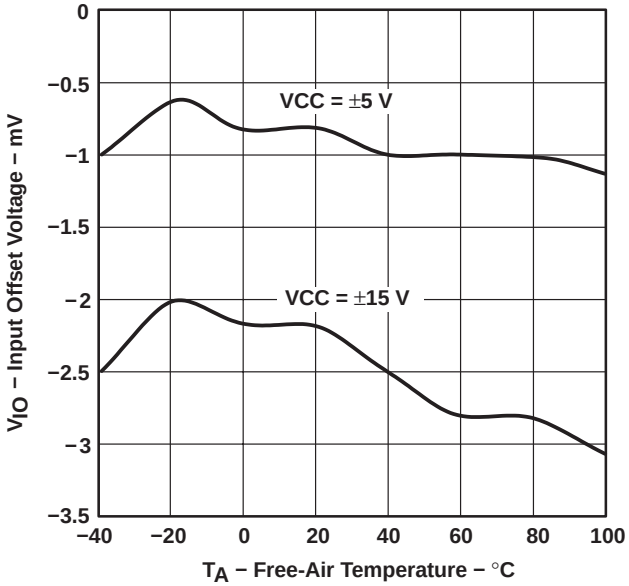

Figure 4

OPEN-LOOP GAIN AND PHASE vs FREQUENCY

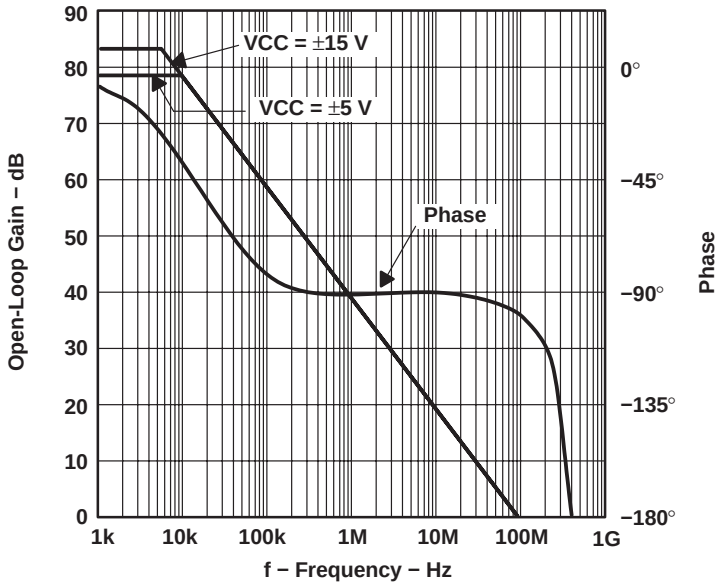

Figure 5

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

TYPICAL CHARACTERISTICS

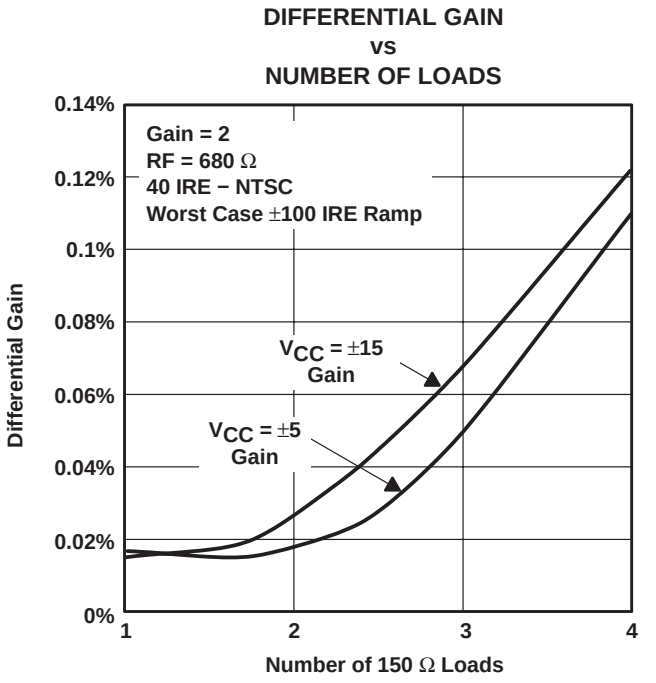

Figure 6

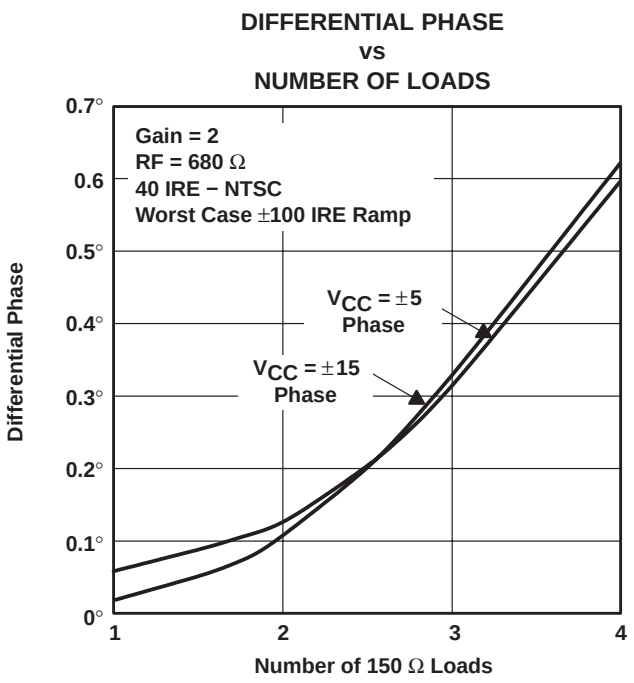

Figure 7

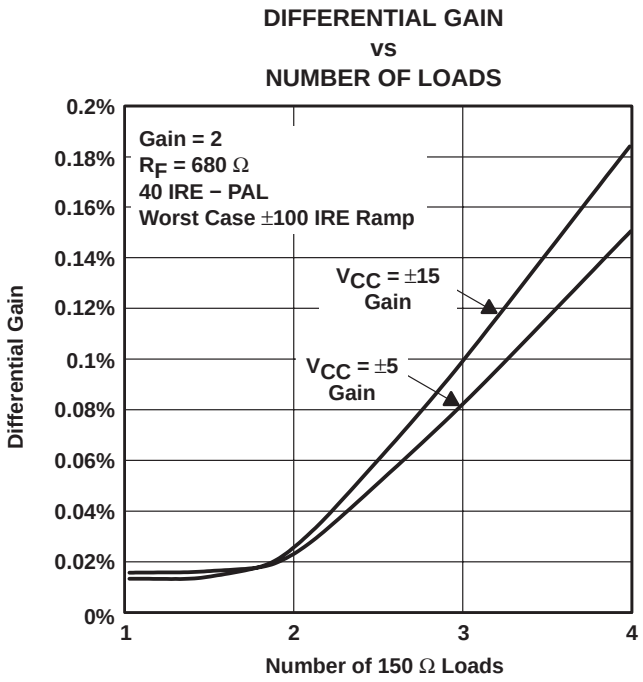

Figure 8

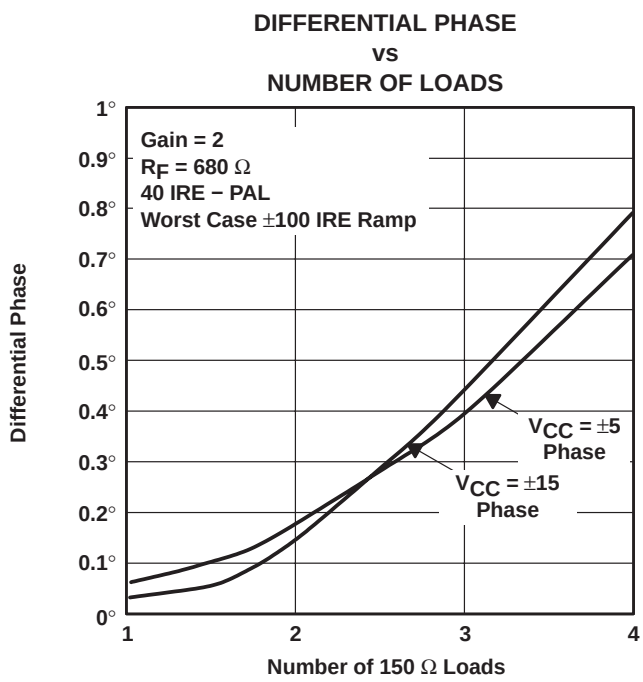

Figure 9

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

TYPICAL CHARACTERISTICS

CLOSED-LOOP GAIN vs FREQUENCY

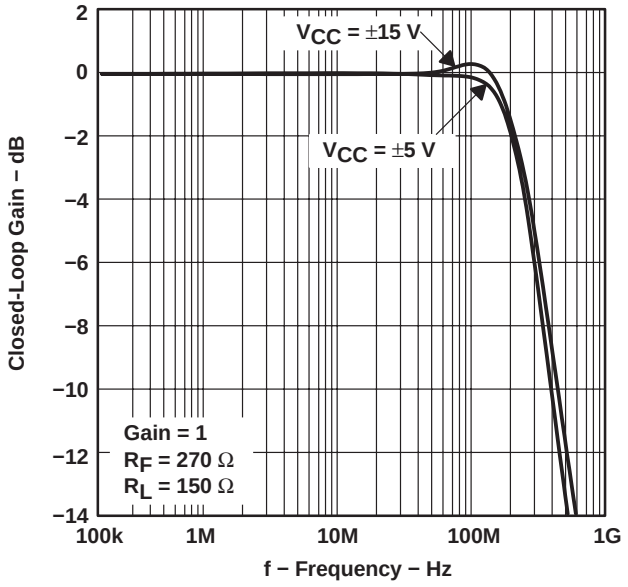

Figure 10

CLOSED-LOOP GAIN vs FREQUENCY

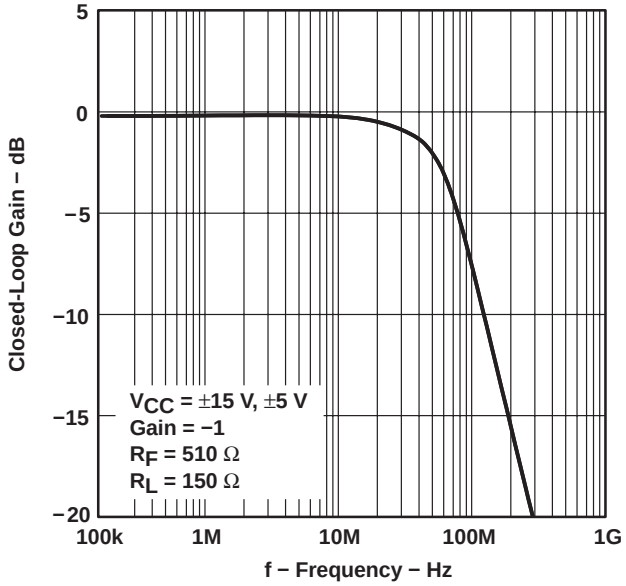

Figure 11

OUTPUT AMPLITUDE vs FREQUENCY

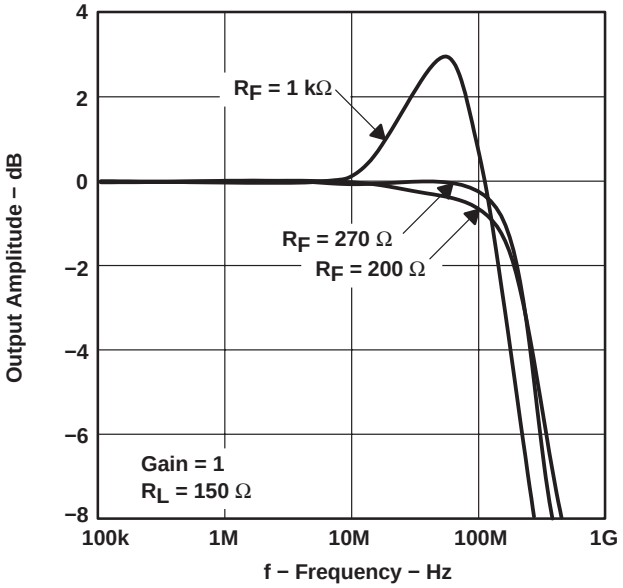

Figure 12

OUTPUT AMPLITUDE vs FREQUENCY

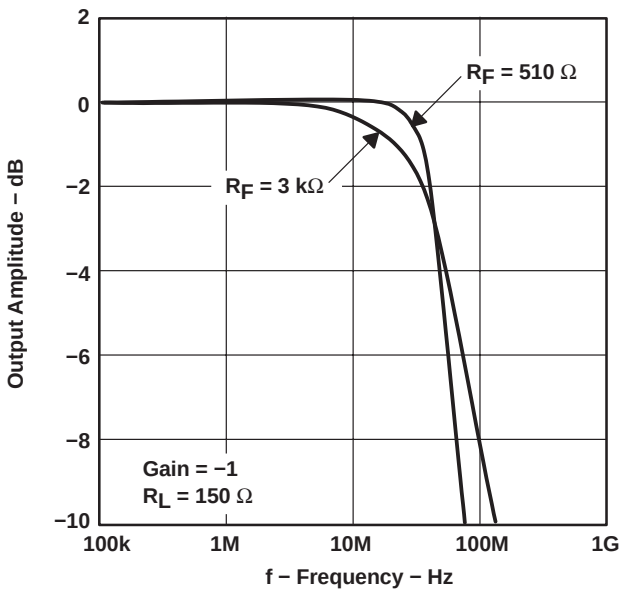

Figure 13

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

TYPICAL CHARACTERISTICS

COMMON-MODE REJECTION RATIO vs FREQUENCY

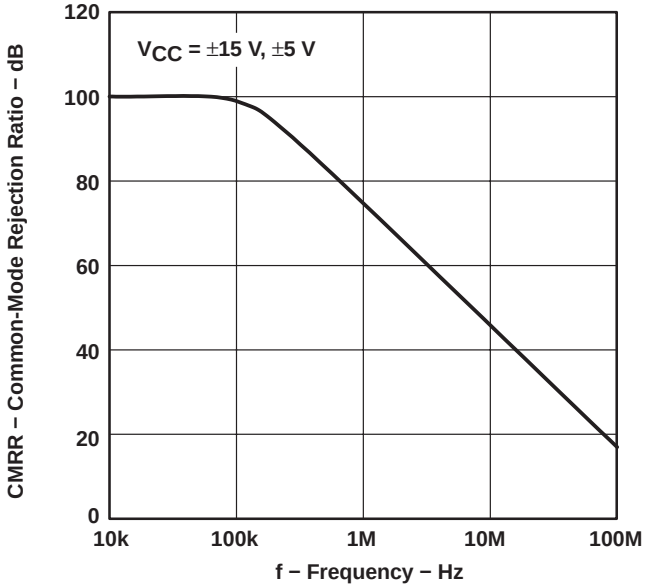

Figure 14

POWER SUPPLY REJECTION RATIO vs FREQUENCY

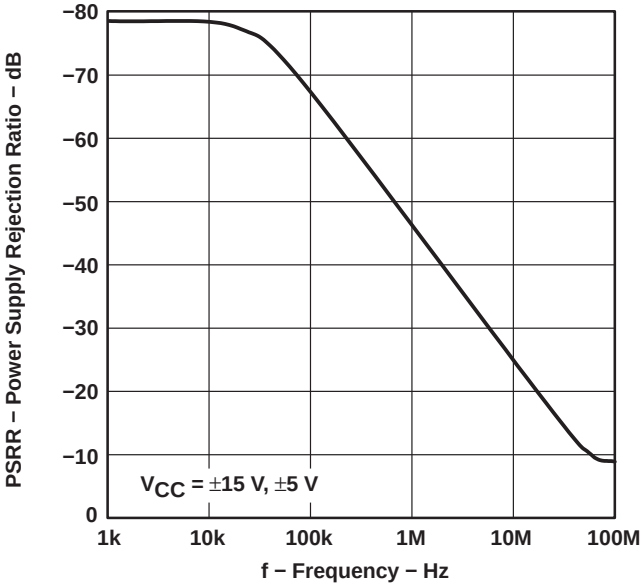

Figure 15

POWER SUPPLY REJECTION RATIO vs FREE-AIR TEMPERATURE

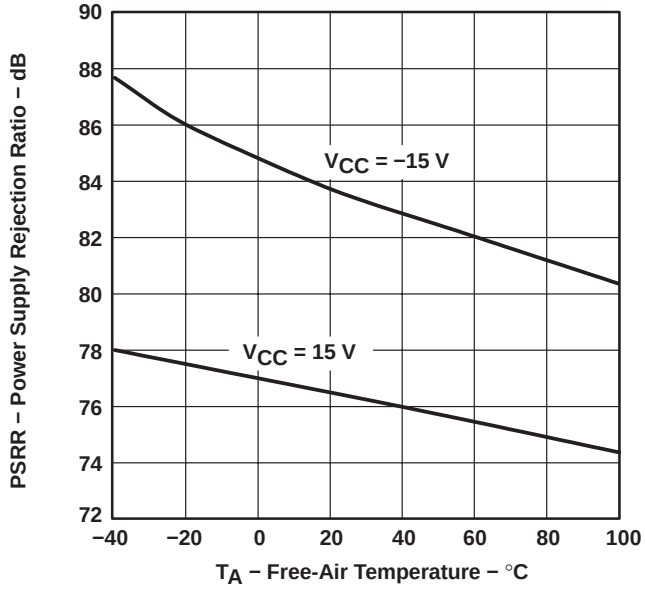

Figure 16

OUTPUT VOLTAGE SWING vs SUPPLY VOLTAGE

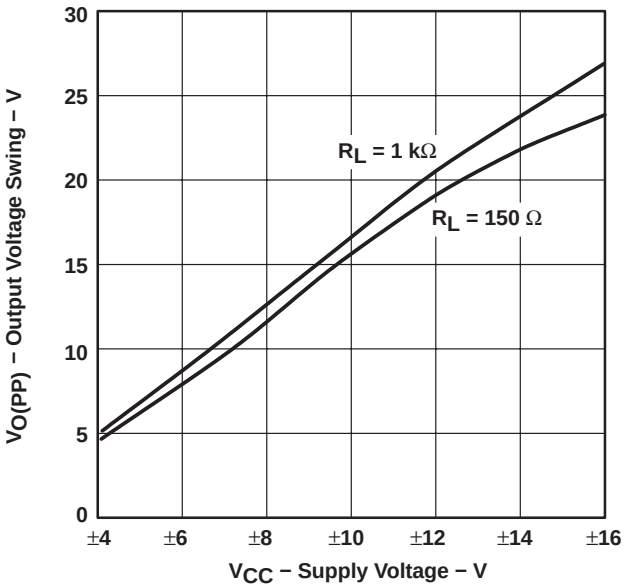

Figure 17

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

TYPICAL CHARACTERISTICS

SUPPLY CURRENT vs FREE-AIR TEMPERATURE

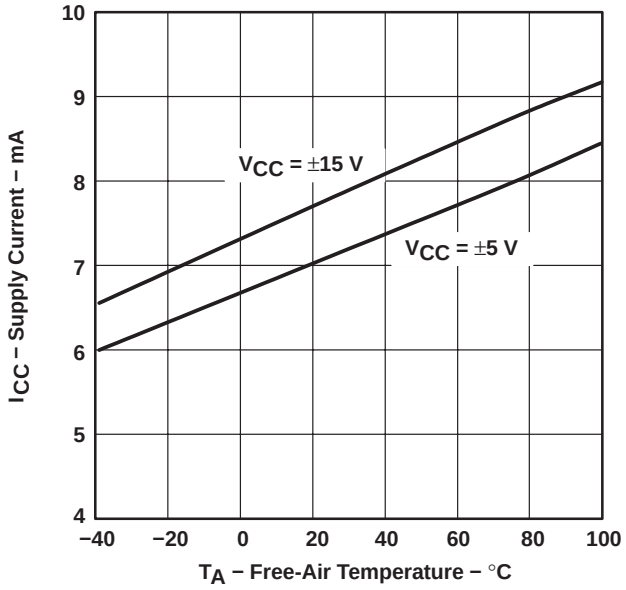

Figure 18

NOISE SPECTRAL DENSITY vs FREQUENCY

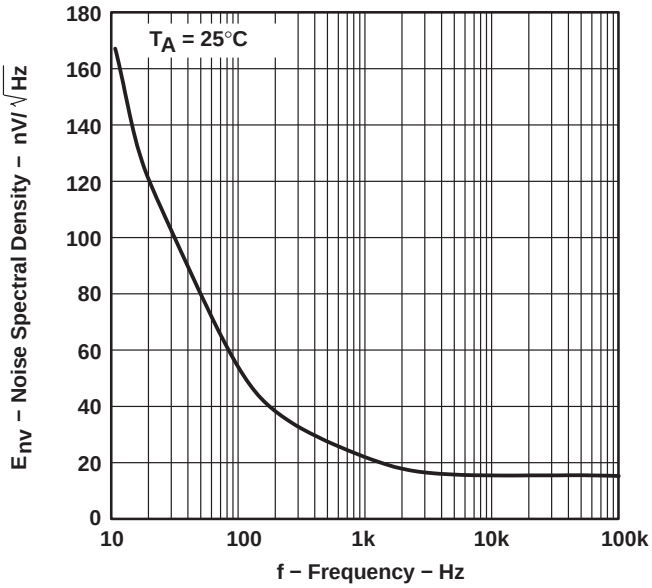

Figure 19

TOTAL HARMONIC DISTORTION vs FREQUENCY

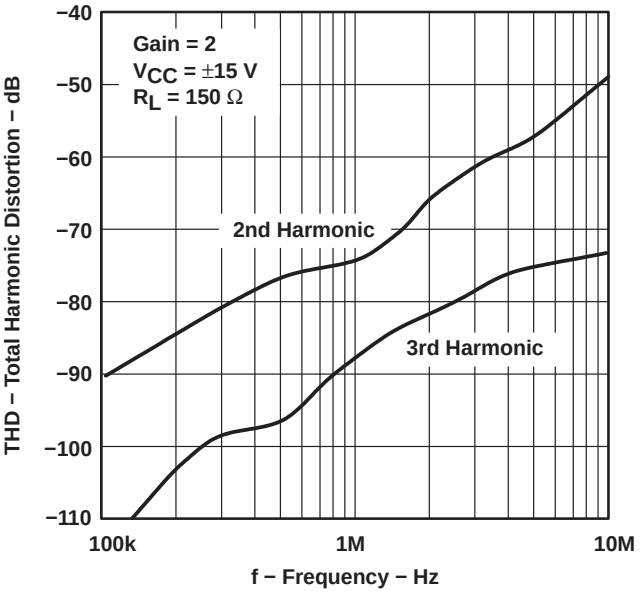

Figure 20

TOTAL HARMONIC DISTORTION vs FREQUENCY

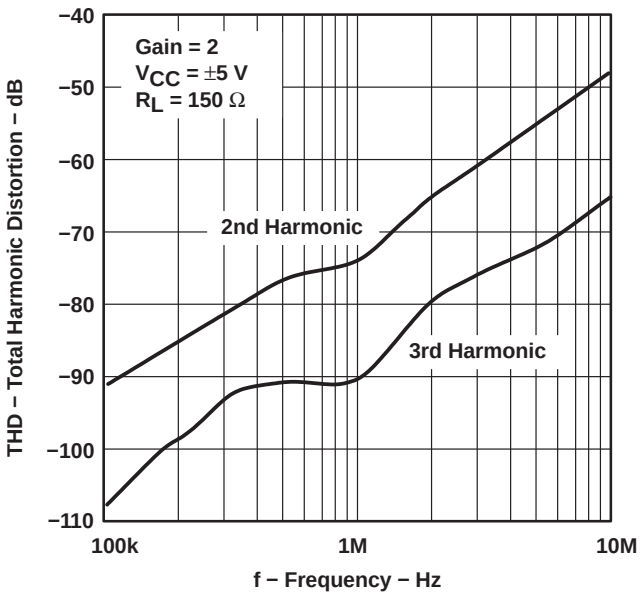

Figure 21

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

TYPICAL CHARACTERISTICS

CROSSTALK vs FREQUENCY

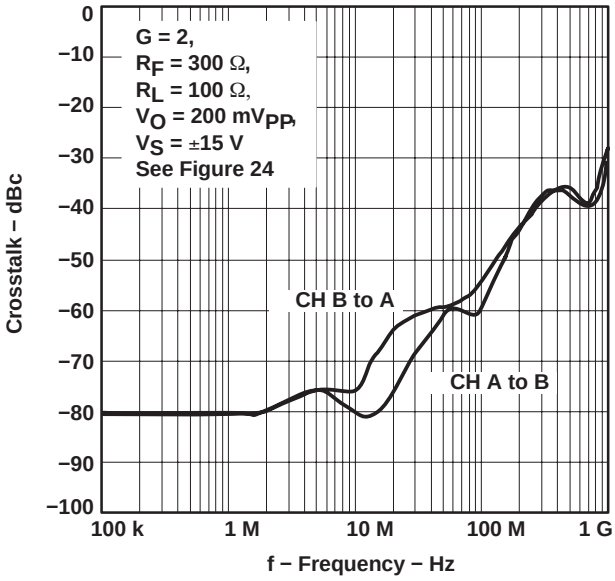

Figure 22

CROSSTALK vs FREQUENCY

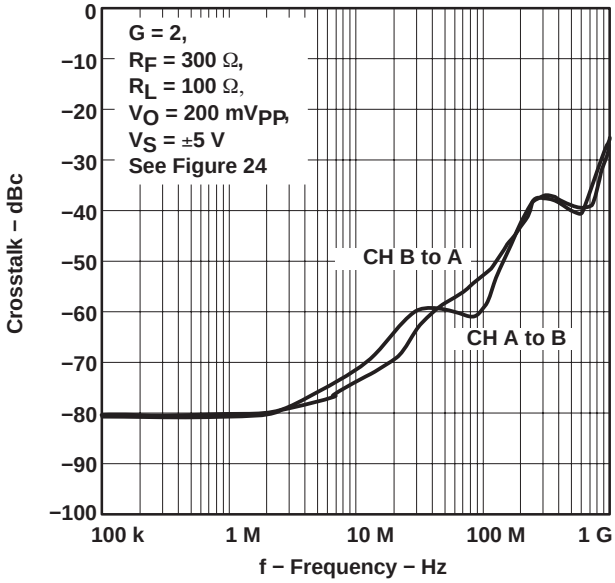

Figure 23

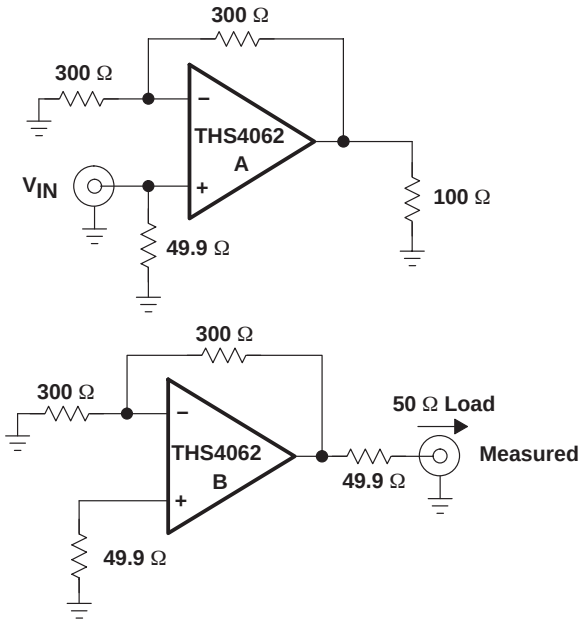

Figure 24. Test Circuits

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

APPLICATION INFORMATION

theory of operation

The THS406x is a high speed, operational amplifier configured in a voltage feedback architecture. It is built using a 30-V, dielectrically isolated, complementary bipolar process with NPN and PNP transistors possessing f_Ts of several GHz. This results in an exceptionally high performance amplifier that has a wide bandwidth, high slew rate, fast settling time, and low distortion. A simplified schematic is shown in Figure 25.

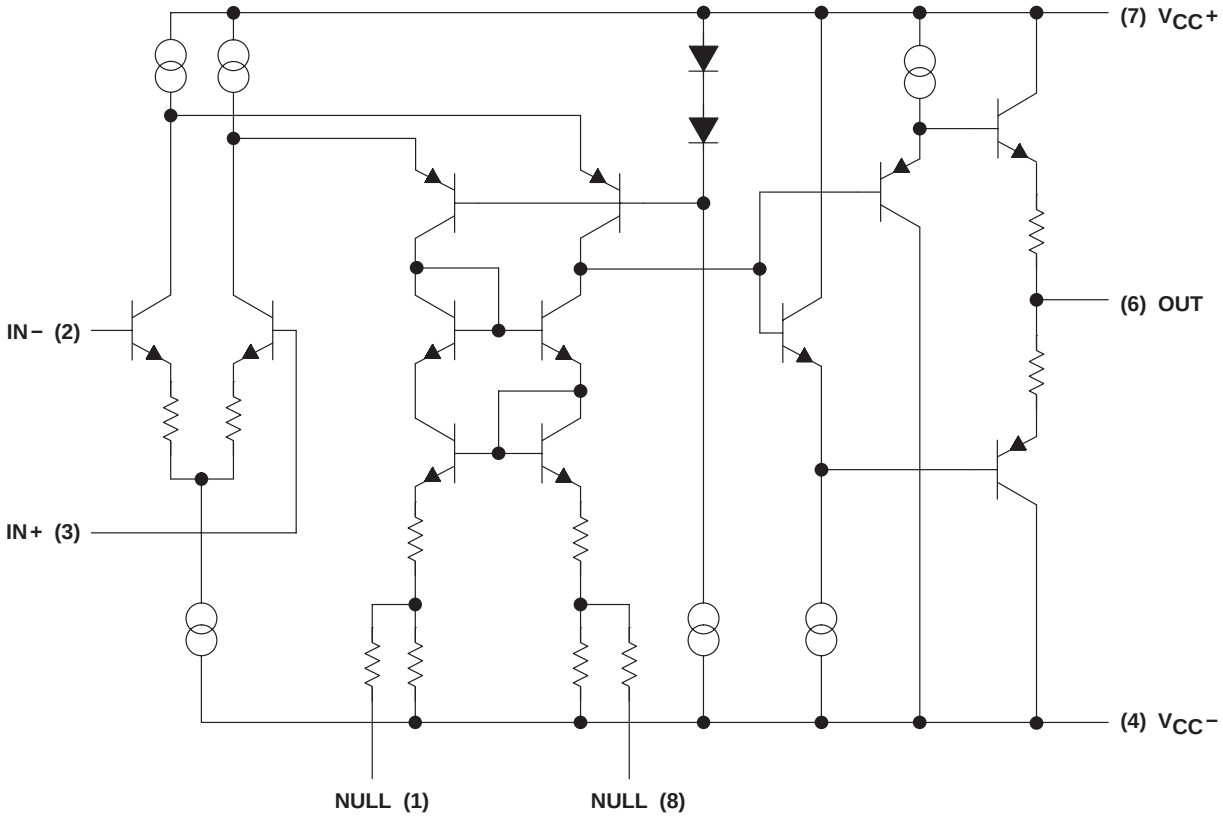

Figure 25. THS4061 Simplified Schematic

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

APPLICATION INFORMATION

offset nulling

The THS4061 has very low input offset voltage for a high-speed amplifier. However, if additional correction is required, an offset nulling function has been provided. By placing a potentiometer between terminals 1 and 8 and tying the wiper to the negative supply, the input offset can be adjusted. This is shown in Figure 26.

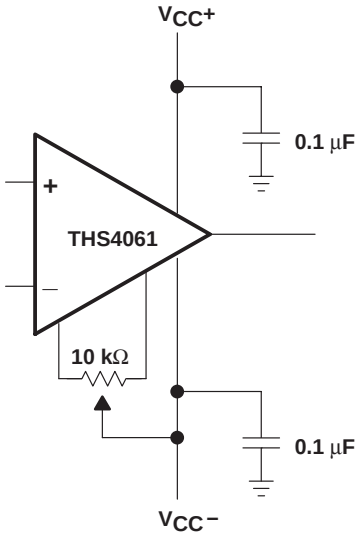

Figure 26. Offset Nulling Schematic

optimizing unity gain response

Internal frequency compensation of the THS406x was selected to provide very wideband performance yet still maintain stability when operated in a noninverting unity gain configuration. When amplifiers are compensated in this manner there is usually peaking in the closed loop response and some ringing in the step response for very fast input edges, depending upon the application. This is because a minimum phase margin is maintained for the G=+1 configuration. For optimum settling time and minimum ringing, a feedback resistor of 270 Ω should be used as shown in Figure 27. Additional capacitance can also be used in parallel with the feedback resistance if even finer optimization is required.

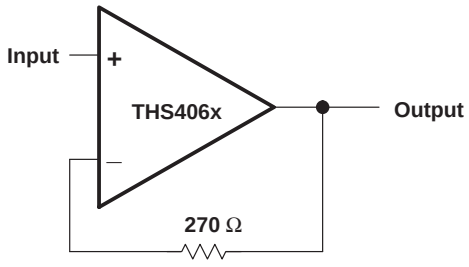

Figure 27. Noninverting, Unity Gain Schematic

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

APPLICATION INFORMATION

driving a capacitive load

Driving capacitive loads with high performance amplifiers is not a problem as long as certain precautions are taken. The first is to realize that the THS406x has been internally compensated to maximize its bandwidth and slew rate performance. When the amplifier is compensated in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series with the output of the amplifier, as shown in Figure 28. A minimum value of 20 Ω should work well for most applications. For example, in 75-Ω transmission systems, setting the series resistor value to 75 Ω both isolates any capacitance loading and provides the proper line impedance matching at the source end.

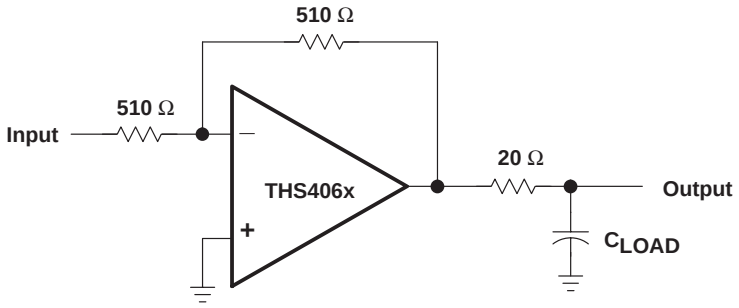

Figure 28. Driving a Capacitive Load

circuit layout considerations

In order to achieve the levels of high frequency performance of the THS406x, it is essential that proper printed-circuit board high frequency design techniques be followed. A general set of guidelines is given below. In addition, a THS406x evaluation board is available to use as a guide for layout or for evaluating the device performance.

- Ground planes − It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling − Use a 6.8-μF tantalum capacitor in parallel with a 0.1-μF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1-μF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1-μF capacitor should be placed as close as possible to the supply terminal. As this distances increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets − Sockets are not recommended for high-speed operational amplifiers. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs/compact part placements − Optimum high frequency performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This helps to minimize stray capacitance at the input of the amplifier.

THS4061IDRG4 Texas Instruments IC VOLTAGE FEEDBACK 1 CIRC 8SOIC

APPLICATION INFORMATION

circuit layout considerations (continued)

- Surface-mount passive components − Using surface-mount passive components is recommended for high-frequency amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout, thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

evaluation board

An evaluation board is available for the THS4061 (literature number SLOP226) and THS4062 (literaure number SLOP235). This board has been configured for very low parasitic capacitance in order to realize the full performance of the amplifier. A schematic of the evaluation board is shown in Figure 29. The circuitry has been designed so that the amplifier may be used in either an inverting or noninverting configuration. To order the evaluation board contact your local TI sales office or distributor. For more detailed information, refer to the *THS4061 EVM User's Manual* (literature number SLOU038) or the *THS4062 EVM User's Manual* (literature number SLOU040)

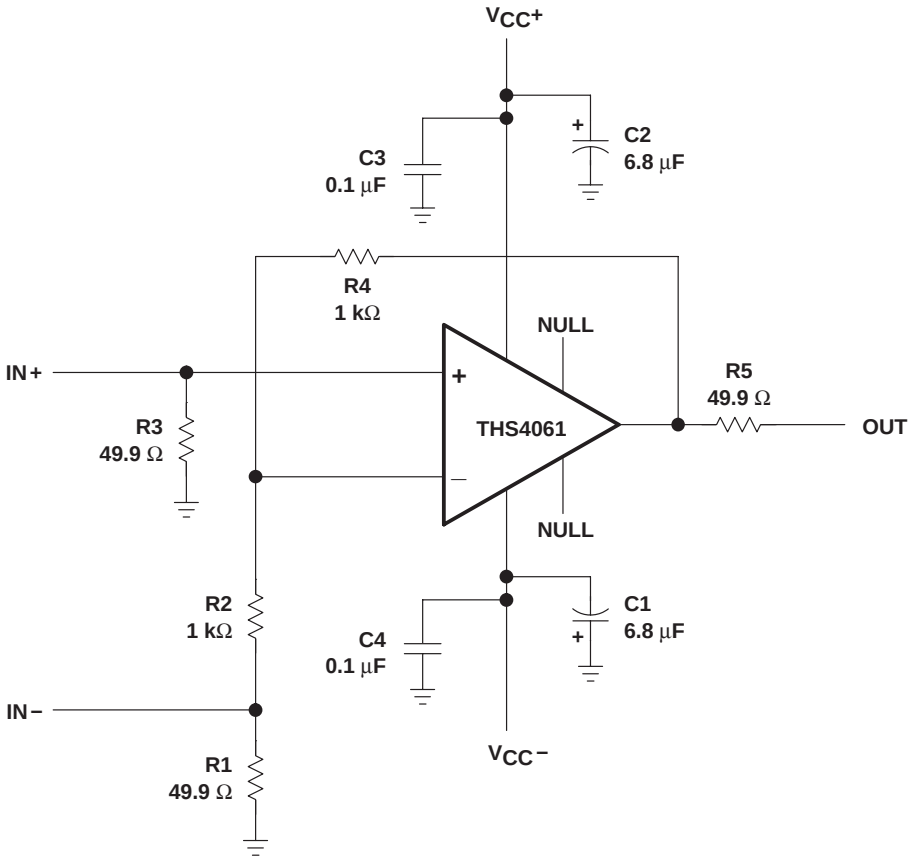

Figure 29. THS4061 Evaluation Board Schematic

TEXAS INSTRUMENTS

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9960101Q2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9960101Q2A THS4061MFKB	Samples
5962-9960101QPA	ACTIVE	CDIP	JG	8	50	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	9960101QPA THS4061M	Samples
THS4061CD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	4061C	Samples
THS4061CDG4	ACTIVE	SOIC	D	8	75	TBD	Call TI	Call TI	0 to 70		Samples
THS4061CDGN	ACTIVE	HVSSOP	DGN	8	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABS	Samples
THS4061CDGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABS	Samples
THS4061CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	4061C	Samples
THS4061ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4061I	Samples
THS4061IDG4	ACTIVE	SOIC	D	8	75	TBD	Call TI	Call TI	-40 to 85		Samples
THS4061IDGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT	Samples
THS4061IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4061I	Samples
THS4061MFKB	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9960101Q2A THS4061MFKB	Samples
THS4061MJG	ACTIVE	CDIP	JG	8	50	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	THS4061MJG	Samples
THS4061MJGB	ACTIVE	CDIP	JG	8	50	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	9960101QPA THS4061M	Samples
THS4062CD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	4062C	Samples
THS4062CDG4	ACTIVE	SOIC	D	8	75	TBD	Call TI	Call TI	0 to 70		Samples
THS4062CDGN	ACTIVE	HVSSOP	DGN	8	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABM	Samples
THS4062CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	4062C	Samples

PACKAGE OPTION ADDENDUM

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
THS4062ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4062I	Samples
THS4062IDGN	ACTIVE	HVSSOP	DGN	8	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABN	Samples
THS4062IDGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABN	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF THS4061, THS4061M :

- Catalog : THS4061
- Military : THS4061M

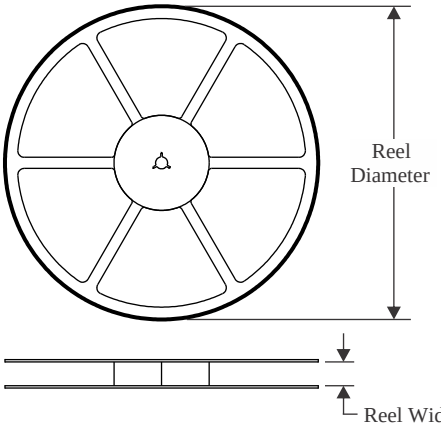
NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

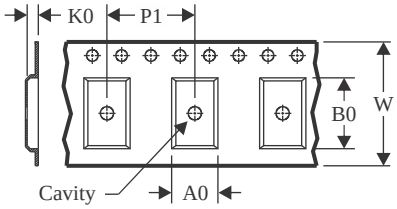
PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

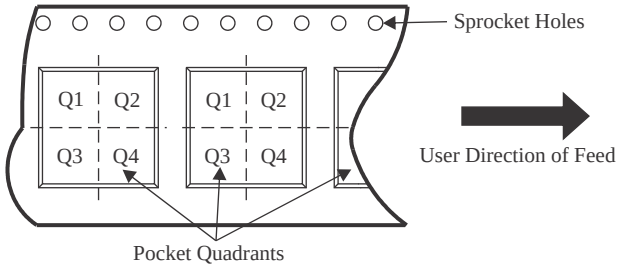


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

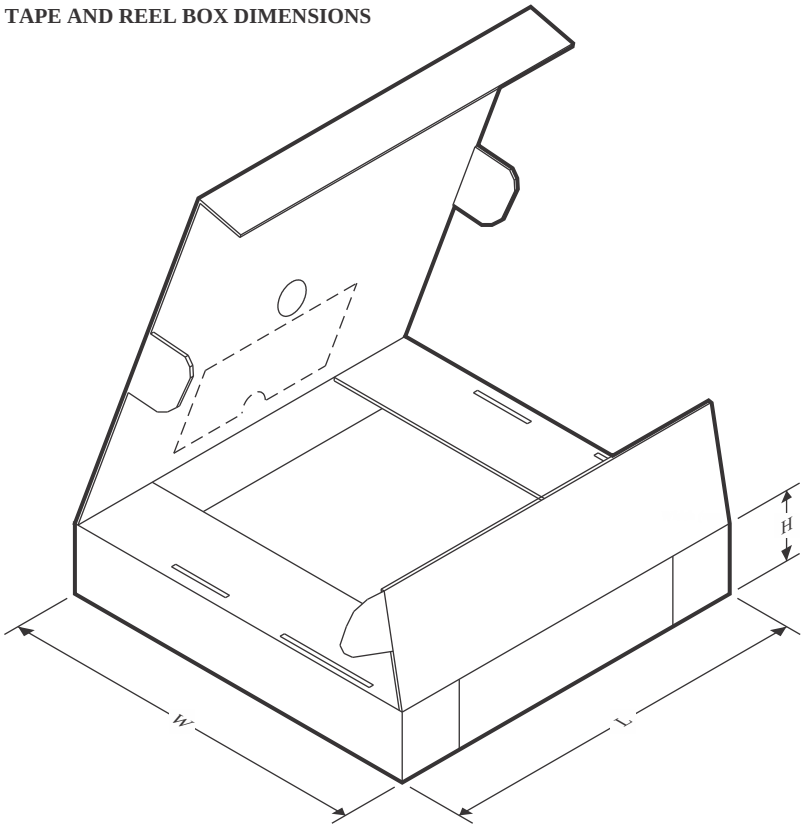


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS4061CDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS4061CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS4061IDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS4061IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS4062CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS4062IDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

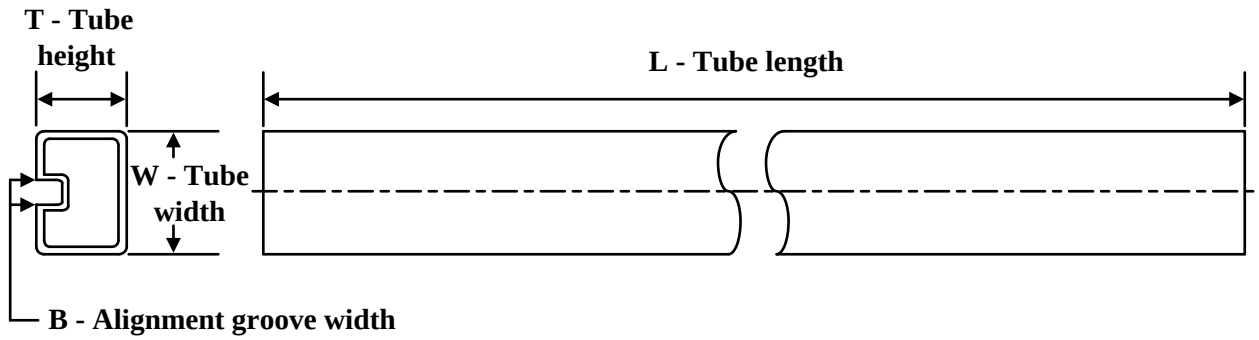


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS4061CDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
THS4061CDR	SOIC	D	8	2500	350.0	350.0	43.0
THS4061IDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
THS4061IDR	SOIC	D	8	2500	350.0	350.0	43.0
THS4062CDR	SOIC	D	8	2500	350.0	350.0	43.0
THS4062IDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0

PACKAGE MATERIALS INFORMATION

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9960101Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
THS4061CD	D	SOIC	8	75	505.46	6.76	3810	4
THS4061ID	D	SOIC	8	75	505.46	6.76	3810	4
THS4061MFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
THS4062CD	D	SOIC	8	75	505.46	6.76	3810	4
THS4062ID	D	SOIC	8	75	505.46	6.76	3810	4

GENERIC PACKAGE VIEW

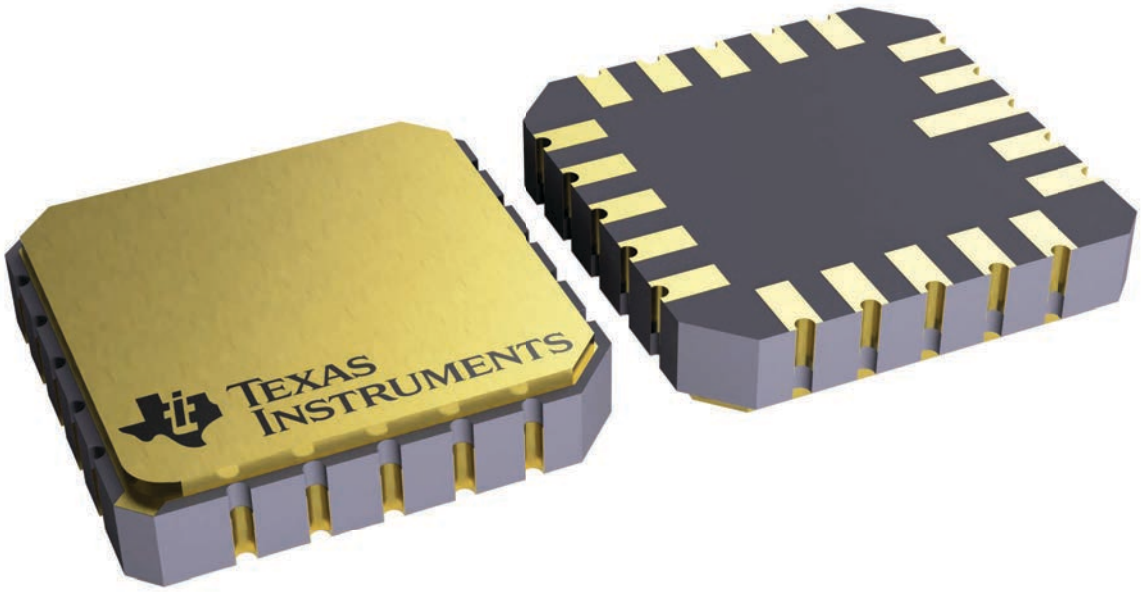
FK 20

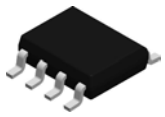
LCCC - 2.03 mm max height

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



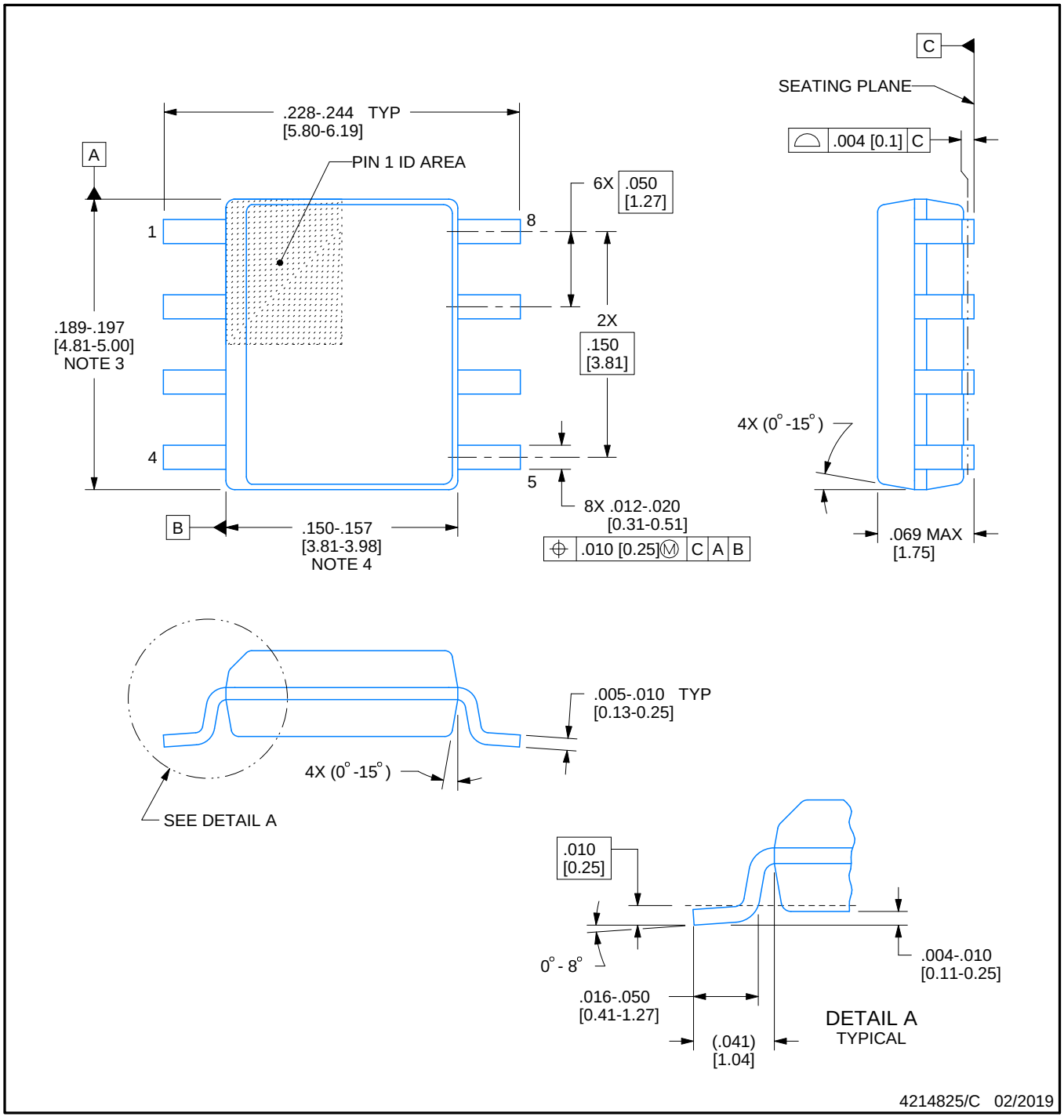


PACKAGE OUTLINE

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

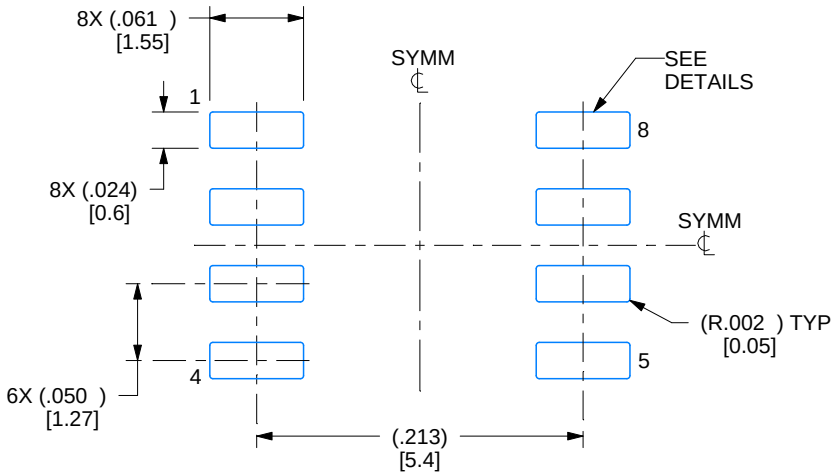
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

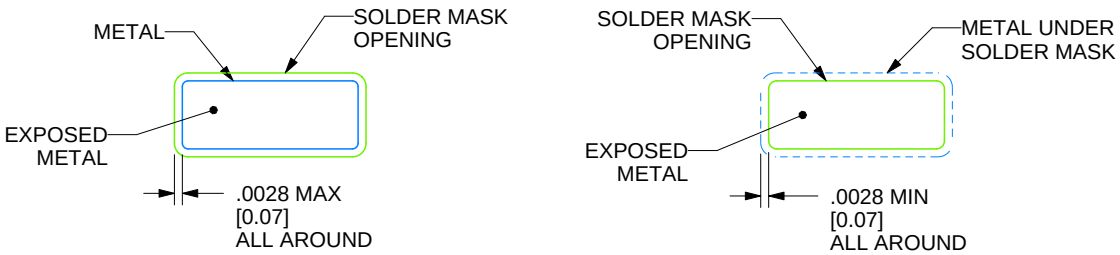
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

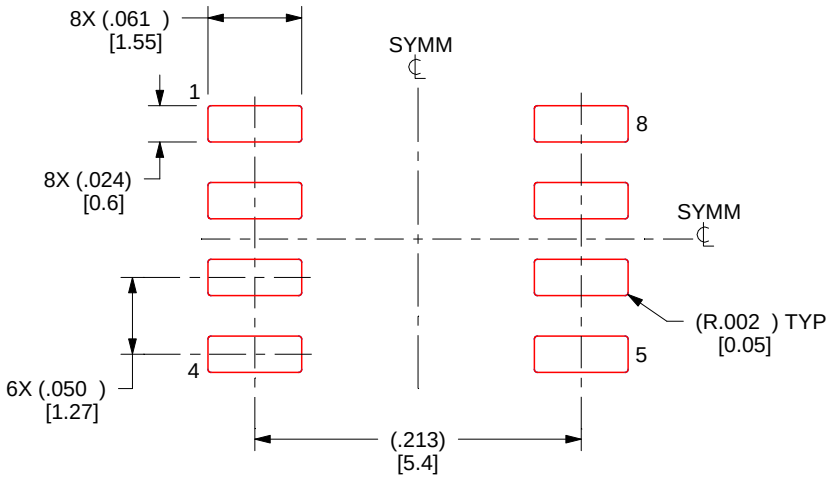
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

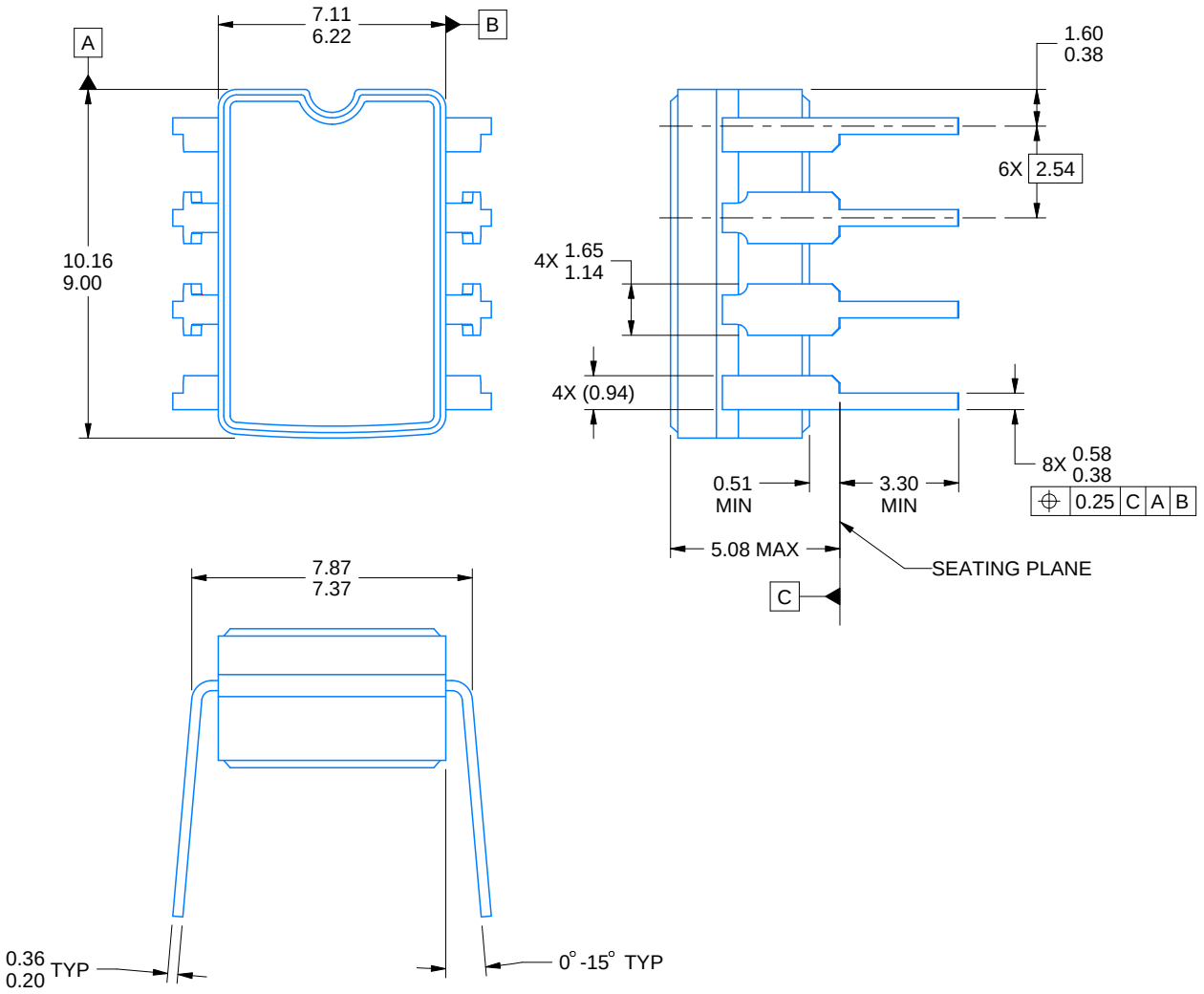
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

JG0008A

CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE



4230036/A 09/2023

NOTES:

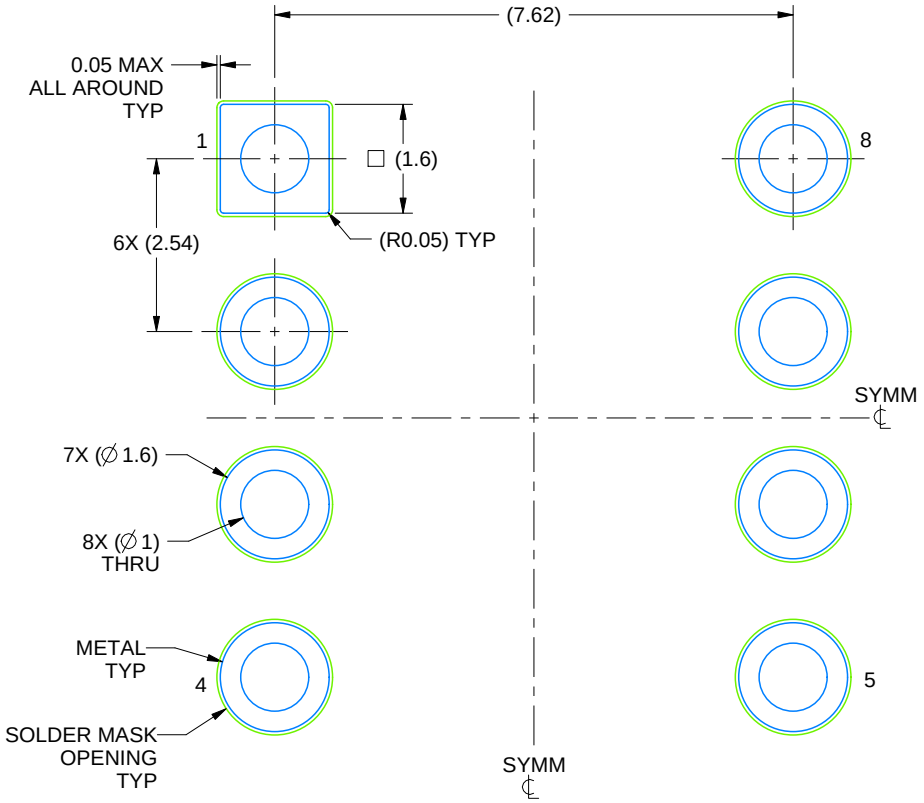
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package can be hermetically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification.
5. Falls within MIL STD 1835 GDIP1-T8

EXAMPLE BOARD LAYOUT

JG0008A

CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE



LAND PATTERN EXAMPLE
NON SOLDER MASK DEFINED
SCALE: 9X

4230036/A 09/2023

GENERIC PACKAGE VIEW

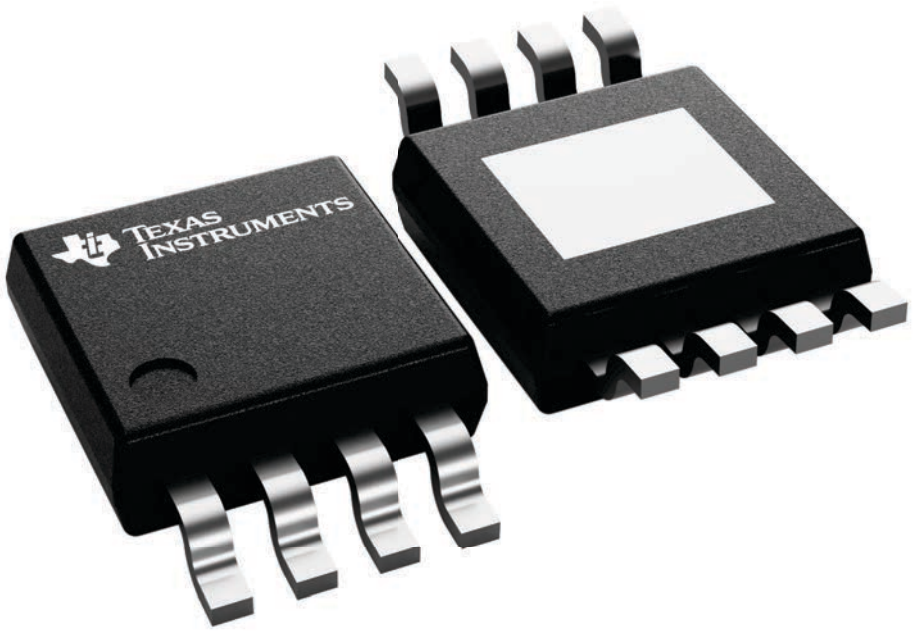
DGN 8

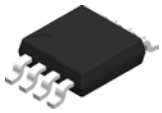
PowerPAD™ HVSSOP - 1.1 mm max height

3 x 3, 0.65 mm pitch

SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



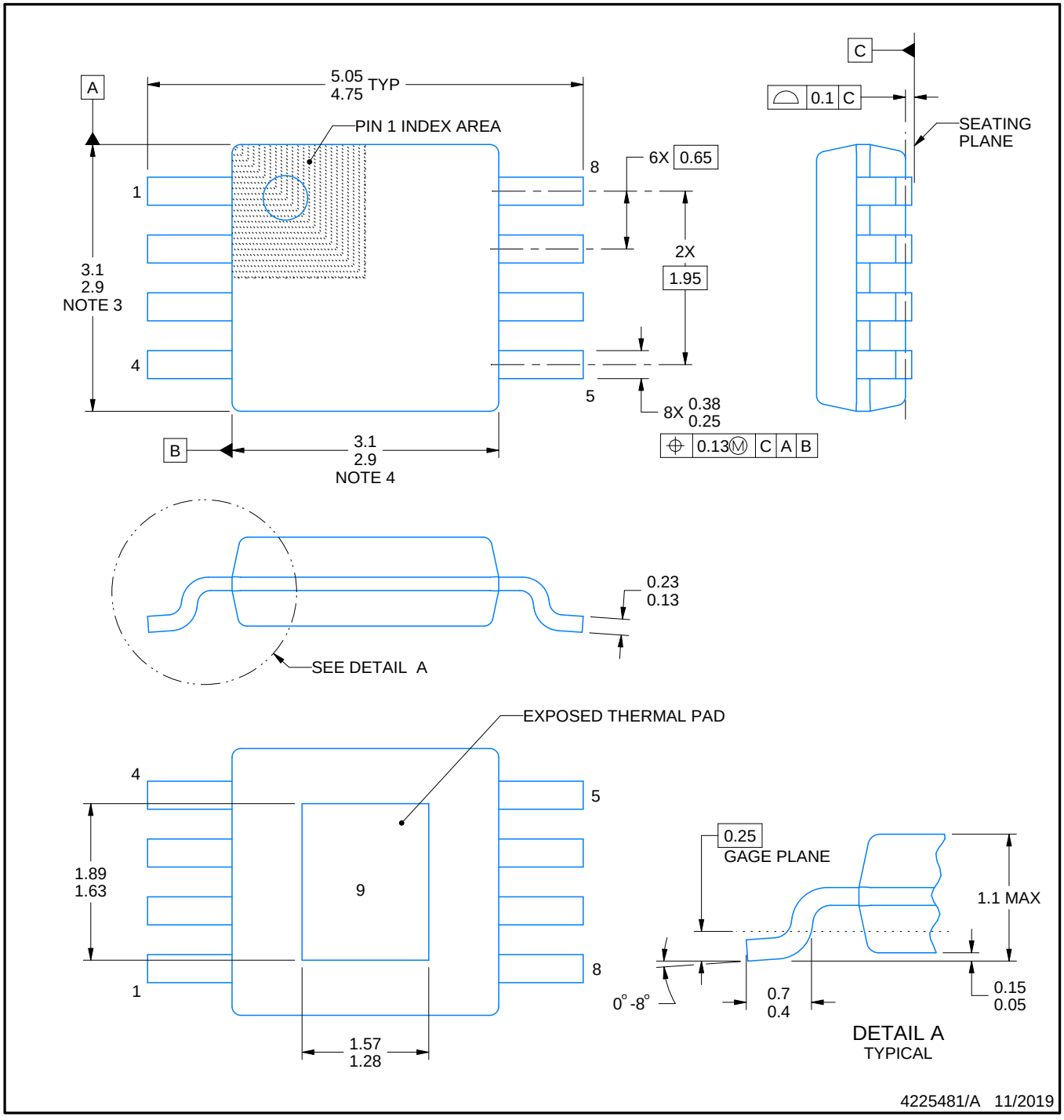


PACKAGE OUTLINE

DGN0008D

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



PowerPAD is a trademark of Texas Instruments.

NOTES:

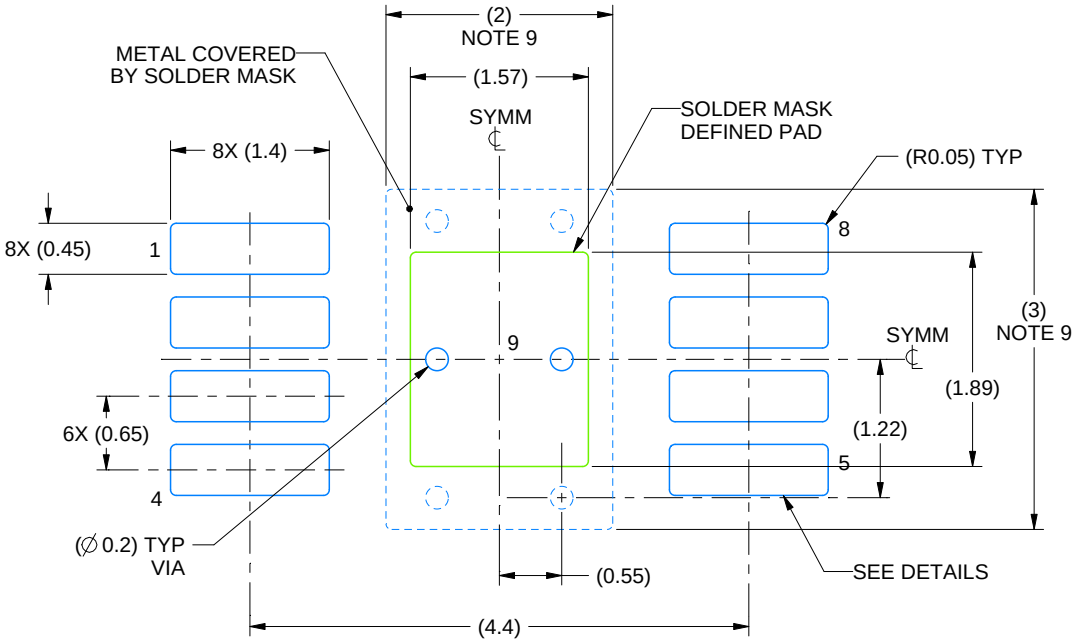
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

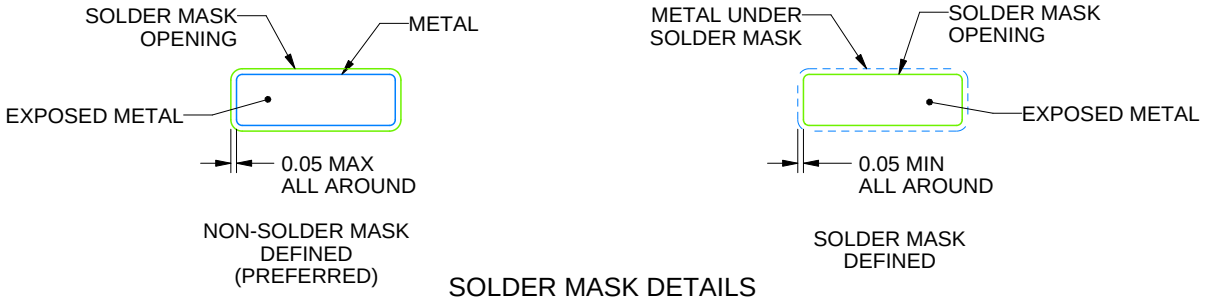
DGN0008D

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4225481/A 11/2019

NOTES: (continued)

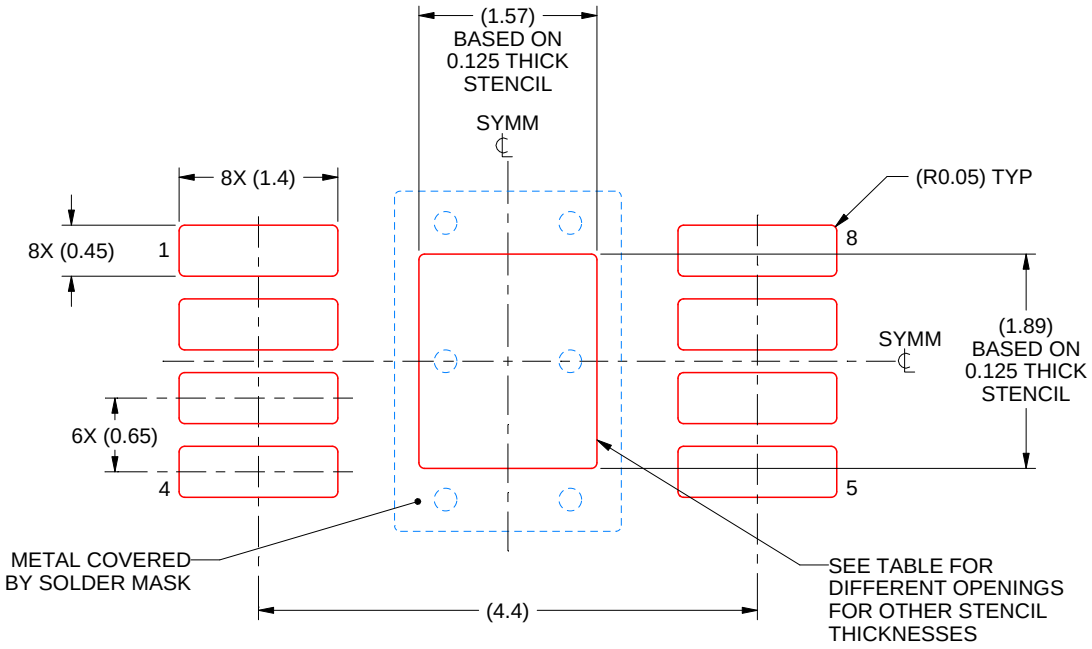
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGN0008D

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.76 X 2.11
0.125	1.57 X 1.89 (SHOWN)
0.15	1.43 X 1.73
0.175	1.33 X 1.60

4225481/A 11/2019

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

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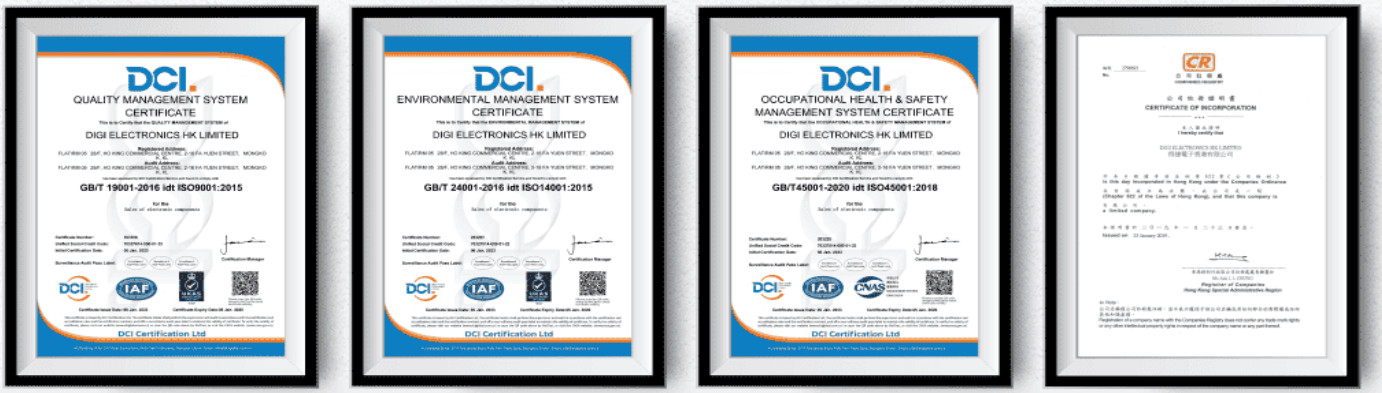

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